

# SKN 71



## Stud Diode

## Rectifier Diode

SKN 71

SKR 71

### Features

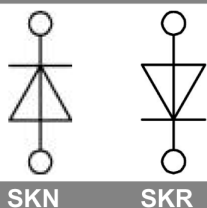
- Reverse voltages up to 1600 V
- Hermetic metal case with glass insulator
- Threaded stud ISO M8 and also 1/4-28 UNF
- SKN: anode to stud, SKR: cathode to stud

### Typical Applications

- All-purpose mean power rectifier diodes
- Cooling via heatsinks
- Non-controllable and half-controllable rectifiers
- Free-wheeling diodes
- Recommended snubber network:  
RC: 0,1  $\mu$ F, 100  $\Omega$  ( $P_R = 2$  W),  
 $R_P = 80$  k $\Omega$  ( $P_R = 6$  W)

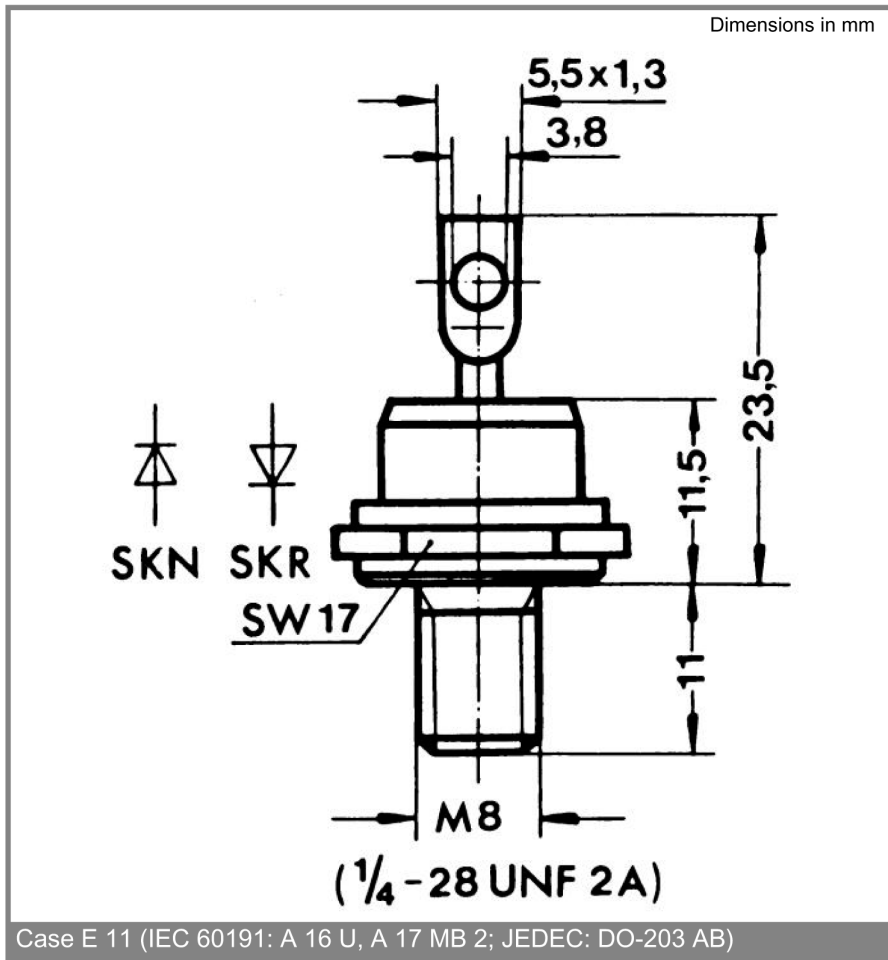
$V_{RSM}$ V	$V_{RRM}$ V	$I_{FRMS} = 150$ A (maximum value for continuous operation) $I_{FAV} = 70$ A (sin. 180; $T_c = 125$ °C)		
400	400	SKN 71/04	SKR 71/04	
800	800	SKN 71/08	SKR 71/08	
1200	1200	SKN 71/12	SKR 71/12	
1400	1400	SKN 71/14	SKR 71/14	
1600	1600	SKN 71/16	SKR 71/16	

Symbol	Conditions	Values	Units
$I_{FAV}$	sin. 180; $T_c = 100$ °C	95	A
$I_D$	K 1,1; $T_a = 45$ °C; B2 / B6	112 / 159	A
	K 1,1F; $T_a = 35$ °C; B2 / B6	174 / 246	A
$I_{FSM}$	$T_{vj} = 25$ °C; 10 ms	1150	A
	$T_{vj} = 180$ °C; 10 ms	1000	A
$i^2t$	$T_{vj} = 25$ °C; 8,3 ... 10 ms	6600	A <sup>2</sup> s
	$T_{vj} = 180$ °C; 8,3 ... 10 ms	5000	A <sup>2</sup> s
$V_F$	$T_{vj} = 25$ °C; $I_F = 200$ A	max. 1,5	V
$V_{(TO)}$	$T_{vj} = 180$ °C	max. 0,85	V
$r_T$	$T_{vj} = 180$ °C	max. 3	m $\Omega$
$I_{RD}$	$T_{vj} = 180$ °C; $V_{RD} = V_{RRM}$	max. 10	mA
$Q_{rr}$	$T_{vj} = 160$ °C; $-di_F/dt = 10$ A/ $\mu$ s	70	$\mu$ C
$R_{th(j-c)}$		0,55	K/W
$R_{th(c-s)}$		0,2	K/W
$T_{vj}$		- 40 ... + 180	°C
$T_{stg}$		- 55 ... + 180	°C
$V_{isol}$		-	V~
$M_s$	to heatsink	4	Nm
$a$		5 * 9,81	m/s <sup>2</sup>
$m$	approx.	30	g
Case		E 11	



SKN

SKR



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